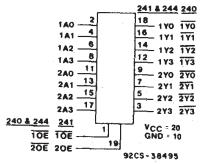
#### **Advance Information**



Data sheet acquired from Harris Semiconductor SCHS287B – Revised January 2004



## Octal Buffer/Line Drivers, 3-State

CD54/74AC/ACT240 - Inverting CD54/74AC/ACT241 - Non-Inverting CD54/74AC/ACT244 - Non-Inverting

#### **Type Features:**

- Buffered inputs
- Typical propagation delay: 3.6 ns @ Vcc = 5 V, T<sub>A</sub> = 25° C, C<sub>L</sub> = 50 pF

## FUNCTIONAL DIAGRAM & TERMINAL ASSIGNMENT

The RCA CD54/74AC240, CD54/74AC241, and CD54/74AC244 and the CD54/74ACT240, CD54/74ACT241, and CD54/74ACT244 3-state octal buffer/line drivers use the RCA ADVANCED CMOS technology. The CD54/74AC/ACT240 and CD54/74AC/ACT244 have active-LOW output enables (10E, 20E). The CD54/74AC/ACT241 has one active-LOW (10E) and one active-HIGH (20E) output enable.

The CD74AC240 and CD74ACT240 are supplied in 20-lead dual-in-line plastic packages (E suffix) and 20-lead small-outline packages (M and M96 suffixes). The CD74AC241 is supplied in 20-lead dual-in-line plastic packages (E suffix) and the CD74ACT241 is supplied in 20-lead dual-in-line plastic packages (E suffix) and 20-lead small-outline packages (M96 suffix). The CD74AC244 and CD74ACT244 are supplied in 20-lead dual-in-line plastic packages (E suffix), 20-lead small-outline packages (M and M96 suffixes), and 20-lead shrink small-outline packages (SM96 suffix). These package types are operable over the following temperature ranges: Commerical (0 to 70°C); Industrial (–40 to +85°C); and Extended Industrial/Military (–55 to + 125°C).

The CD54AC240 and CD54AC244 and the CD54ACT240, CD54ACT241, and CD54ACT244 are supplied in 20-lead hermetic dual-in-line ceramic packages (F3A suffix) and are operable over the -55 to +125°C temperature range.

#### **Family Features:**

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latch-up-resistant CMOS process and circuit design
- Speed of bipolar FAST\*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
  - Fanout to 15 FAST\* ICs
  - Drives 50-ohm transmission lines

#### TRUTH TABLES

	INPUTS			
10E, 20E	10E, 20E A			
L	L	Н		
L	Н	L		
Н	X	Z		

(AC/ACT240)

INPU	ITS	OUTPUT
10E, 20E	Α	Y
L	, L	L
L	Н	Н
н	X	Z

(AC/ACT244)

INP	UTS	OUTPUT	PUT INPUTS		OUTPUT
10E	1A	1Y	20E	2A	2Y
L	L	L	L	Х	Z
L	н	H	н	L	L
Н	х	Z	Н	н	н

(AC/ACT241)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Z = HIGH Impedance

This data sheet is applicable to the CD54/74AC240, CD54ACT240, and CD54/74ACT241. The CD54/74AC241 were not acquired from Harris Semiconductor. See SCHS244 for information on the CD74ACT240, CD74AC244, and CD74ACT244. Copyright © 2004, Texas Instruments Incorporated

<sup>\*</sup>FAST is a Registered Trademark of Fairchild Semiconductor Corp.

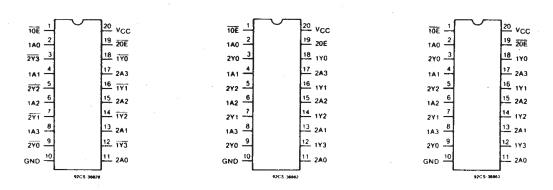
MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE (V∞)0.5 to 6 V
DC INPUT DIODE CURRENT, $I_{iK}$ (for $V_i < -0.5$ V or $V_i > V_{cc} + 0.5$ V)
DC OUTPUT DIODE CURRENT, $l_{OK}$ (for $V_0 < -0.5$ V or $V_0 > V_{CC} + 0.5$ V)
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, Io (for Vo > -0.5 V or Vo < Vcc + 0.5 V) ±50 mA
DC V <sub>CC</sub> or GROUND CURRENT (I <sub>CC</sub> or I <sub>GND</sub> )
POWER DISSIPATION PER PACKAGE (PD):
For T <sub>A</sub> = -40 to +85°C (Package Type E)
For T <sub>A</sub> = -40 to +70°C (Package Type M)
For T <sub>A</sub> = +70 to +85°C (Package Type M)
For T <sub>A</sub> = +70 to +85°C (Package Type M)
For $T_A = +70$ to $+85^{\circ}$ C (Package Type M)
For $T_A$ = +70 to +85°C (Package Type M)
For $T_A = +70$ to $+85^{\circ}$ C (Package Type M)
For $T_A = +70$ to $+85^{\circ}$ C (Package Type M) . Derate Linearly at 6 mW/°C to 310 mW OPERATING-TEMPERATURE RANGE ( $T_A$ ): CD5455 to $+125^{\circ}$ C CD7440 to $+85^{\circ}$ C STORAGE TEMPERATURE ( $T_{stg}$ )65 to $+150^{\circ}$ C LEAD TEMPERATURE (DURING SOLDERING):

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC			LIMITS		
CHARACTERISTIC	MIN.	MAX.	UNITS		
Supply-Voltage Range, V <sub>CC</sub> *:					
(For T <sub>A</sub> = Full Package-Temperature Range)					
AC Types	1.5	5.5	V		
ACT Types	4.5	5.5	V		
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>		0	VCC	٧	
Operating Temperature, T <sub>A</sub>	CD54	-55	+125	°C	
	CD74	-40	+85	C	
Input Rise and Fall Slew Rate, dt/dv					
at 1.5 V to 3 V (AC Types)		0	50	ns/V	
at 3.6 v to 5.5 V (AC Types)		0	20	ns/V	
at 4.5 V to 5.5 V (ACT Types)		0	10	ns/V	

<sup>\*</sup> Unless otherwise specified, all voltages are referenced to ground.



CD54/74AC, ACT240 TYPES TERMINAL ASSIGNMENT

CD54/74AC, ACT241 TYPES TERMINAL ASSIGNMENT CD54/74AC, ACT244 TYPES TERMINAL ASSIGNMENT

STATIC ELECTRICAL CHARACTERISTICS: AC Series

					AMBIENT TEMPERATURE (TA) - °C								
CHARACTERISTI	CS	TEST CO	NDITIONS	V <sub>cc</sub>	+:	25	40 t	o +85	-55 to	+125	UNITS		
		V, (V)	l <sub>o</sub> (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.			
High-Level Input				1.5	1.2		1.2		1.2				
Voltage	VIH			3	2.1		2.1		2.1	—	v		
				5.5	3.85	<u> </u>	3.85		3.85				
Low-Level Input				1.5	_	0.3	<b>—</b>	0.3		0.3			
Voltage	VIL			3		0.9	_	0.9		0.9	V		
				5.5	_	1.65	_	1.65	_	1.65	<u> </u>		
High-Level Output	,		-0.05	1.5	1.4		1.4	_	1.4				
Voltage	V <sub>OH</sub>	ViH	-0.05	3	2.9		2.9	_	2.9				
		or	-0.05	4.5	4.4		4.4	_	4.4	_	]		
		V <sub>IL</sub>	-4	3	2.58	_	2.48		2.4		V		
			-24	4.5	3.94	· ·	3.8	_	3.7	_			
		#, * {	-75	5.5	-		3.85		_	<u> </u>			
		"'	-50	5.5		_	_		3.85		]		
Low-Level Output			0.05	1.5	_	0.1	_	0.1	_	0.1			
Voltage	VOL	V <sub>IH</sub>	0.05	3		0.1	_	0.1	_	0.1			
		or	0.05	4.5		0.1		0.1	_	0.1			
		VIL	12	3	_	0.36	_	0.44	_	0.5	] v		
					24	4.5	_	0.36	_	0.44	_	0.5	
		#, * {	75	5.5	_			1.65	_	-			
		"· ~ {	50	5.5			_	_	· · -	1.65	1		
Input Leakage Current	l <sub>t</sub>	V <sub>CC</sub> or GND		5.5	_	±0.1	<u>-</u>	±1	_	±1	μΑ		
3-State Leakage Current	loz	V <sub>IH</sub>											
		V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub>		5.5		±0.5	-	±5		±10	μΑ		
		or GND											
Quiescent Supply Current, MSI	loc	V <sub>∞</sub> or GND	0	5.5	_	8		80	_	160	μΑ		

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

<sup>\*</sup>Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

#### STATIC ELECTRICAL CHARACTERISTICS: ACT Series

		. ,			AMBIENT TEMPERATURE (TA) - °C						
CHARACTERISTI	cs	TEST CO	NDITIONS	V <sub>cc</sub>	+	25	-40 t	o +85	-55 to	+125	UNITS
		V, (V)	l <sub>o</sub> (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V <sub>IH</sub>			4.5 to 5.5	2	_	2		2	_	V
Low-Level Input Voltage	VıL			4.5 to 5.5	_	0.8		0.8		0.8	V
High-Level Output		V <sub>IH</sub> or	-0.05	4.5	4.4		4.4	-	4.4	_	
Voltage	V <sub>OH</sub>	V <sub>IL</sub>	-24	4.5	3.94		3.8	_	3.7		V
		#, * {	-75	5.5			3.85				
			-50	5.5				_	3.85		<u> </u>
Low-Level Output		ViH	0.05	4.5		0.1		0.1		0.1	
Voltage	$V_{OL}$	or V <sub>IL</sub>	24	4.5		0.36		0.44		0.5	V
_		#, * {	75	5.5				1.65			
		, l	50	5.5						1.65	
Input Leakage Current	t <sub>i</sub>	V <sub>CC</sub> or GND		5.5		±0.1	<u> </u>	±1	_	±1	μА
3-State Leakage Current	loz	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> =		5.5	_	±0.5		±5		±10	μΑ
	·	V <sub>cc</sub> or GND									
Quiescent Supply Current, MSI	lcc	V <sub>∞</sub> or GND	0	5.5		8		80	_	160	μΑ
Additional Quiescent S Current per Input Pir TTL Inputs High 1 Unit Load		V <sub>cc</sub> -2.1	·	4.5 to 5.5	_	2.4		2.8	_	3	mA

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

#### **ACT INPUT LOADING TABLES**

CD54/74ACT240					
INPUT UNIT LOADS*					
nA0 - A3	1.42				
10E	0.83				
20E	0.83				

CD54/74ACT241						
INPUT UNIT LOADS						
nA0 - A3	0.5					
10E	0.83					
20E	1.67					

CD54/74ACT244							
INPUT	INPUT UNIT LOADS*						
nA0 - A3	0.5						
10E	0.83						
20E	0.83						

<sup>\*</sup>Unit load is ∆I<sub>∞</sub> limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

SWITCHING CHARACTERISTICS: AC Series;  $t_{\rm r}$   $t_{\rm r}$  = 3 ns,  $C_{\rm L}$  = 50 pF

			AMBII	T .				
CHARACTERISTICS	SYMBOL	V <sub>cc</sub>		o +85		+125	UNITS	
	'	(V)	MIN.	MAX.	MIN.	MAX.	]	
Propagation Delays: Data to Outputs AC240	t <sub>PLH</sub>	1.5 :3.3* 5†	2.6 1.9	82 9.2 6.5	 2.5 1.8	90 10.1 7.2	ns	
AC241, 244	: tегн tенс	1.5 3.3 5		93 10.5 7.5	_ 2.9 2.1	103 11.5 8.2	ns	
Output Enable Times	t <sub>PZL</sub>	1.5 3.3 5	 4.6 3.1	136 16.4 10.9	_ 4.5 3	150 18 12	ns	
Output Disable Times	t <sub>PLZ</sub> t <sub>PHZ</sub>	1.5 3.3 5	3.9 3.1	136 13.6 10.9	 3.8 3	150 15 12	ns	
Power Dissipation Capacitance AC240 AC241, 244	C <sub>PD</sub> §		65 Typ. 65 Typ. 71 Typ. 71 Typ.		pF			
Min. (Valley) V <sub>OH</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5	4 Typ. @ 25°C			V		
Max. (Peak) V <sub>OL</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5	1 Тур. @ 25°С			V		
Input Capacitance	Cı	_		10	_	10	pF	
3-State Output Capacitance	Co			15		15	pF	

#### SWITCHING CHARACTERISTICS: ACT Series; t,, t, = 3 ns, C, = 50 pF

		V <sub>cc</sub> (V)	AMBI	(A) - °C				
CHARACTERISTICS	SYMBOL		-40	-40 to +85		+125	UNITS	
	}		MIN.	MAX.	MIN.	MAX.		
Propagation Delays: Data to Outputs ACT240	t <sub>PLH</sub> t <sub>PHL</sub>	5†	2.3	7.8	2.2	8.6	ns	
ACT241, 244	t <sub>PLH</sub> t <sub>PHL</sub>	5	2.5	8.7	2.4	9.6	ns	
Output Enable Times	t <sub>PZL</sub>	5	3.5	12.2	3.4	13.4	ns	
Output Disable Times	t <sub>PLZ</sub>	5	3.5	12.2	3.4	13.4	ns	
Power Dissipation Capacitance ACT240 ACT241, 244	C <sub>PO</sub> §		65 Typ. 65 Typ. 71 Typ. 71 Typ.			pF		
Min. (Valley) V <sub>он</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5	4 Typ. @ 25°C		V			
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5	1 Typ. @ 25°C		v			
Input Capacitance	Cı		_	10	_	10	pF	
3-State Output Capacitance	Co		_	15	_	15	ρF	

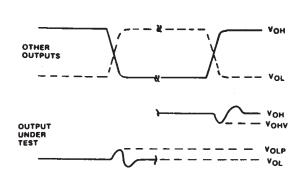
<sup>\*3.3</sup> V: min. is @ 3.6 V max. is @ 3 V

 $\ddagger C_{PD}$  is used to determine the dynamic power consumption, per package. For AC series:  $P_D = V_{CC}^2 \, f_i \, (C_{PD} + C_L)$  For ACT series:  $P_D = V_{CC}^2 \, f_i \, (C_{PD} + C_L) + V_{CC} \, \Delta I_{CC}$  where  $f_i$  = input frequency

†5 V: min. is @ 5.5 V max. is @ 4.5 V  $C_L$  = output load capacitance

 $V_{CC} = supply voltage$ 

#### PARAMETER MEASUREMENT INFORMATION



#### NOTES:

- VOHY AND VOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.
   INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS:
- PRR ≤ 1 MHz, t<sub>1</sub> = 3 ns, t<sub>1</sub> = 3 ns, 5 KEW 1 ns.

  R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED.
  IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 F CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

9205-42406

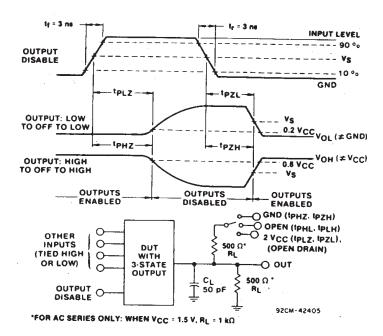
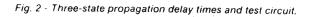
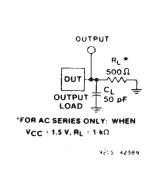
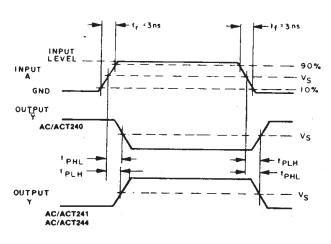


Fig. 1 - Simultaneous switching transient waveforms.







9205-42407

Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	<b>CD54/74ACT</b>
Input Level	V <sub>cc</sub>	3 V
Input Switching Voltage, Vs	0.5 V <sub>cc</sub>	1.5 V
Output Switching Voltage, Vs	0.5 V <sub>cc</sub>	0.5 V <sub>CC</sub>





4-Feb-2021

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD54AC240F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54AC240F3A	Samples
CD54AC244F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54AC244F3A	Samples
CD54ACT240F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54ACT240F3A	Samples
CD54ACT241F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54ACT241F3A	Samples
CD54ACT244F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54ACT244F3A	Samples
CD74AC240E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74AC240E	Samples
CD74AC240EE4	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74AC240E	Samples
CD74AC240M	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC240M	Samples
CD74AC240M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC240M	Samples
CD74AC244E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74AC244E	Samples
CD74AC244M	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC244M	Samples
CD74AC244M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC244M	Samples
CD74ACT240E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT240E	Samples
CD74ACT240M	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT240M	Samples
CD74ACT240M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT240M	Samples
CD74ACT240M96E4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT240M	Samples
CD74ACT241E	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT241E	Samples
CD74ACT241M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT241M	Samples
CD74ACT244E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT244E	Samples



#### PACKAGE OPTION ADDENDUM

4-Feb-2021

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74ACT244M	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT244M	Samples
CD74ACT244M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT244M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54AC240, CD54AC244, CD54ACT240, CD54ACT241, CD54ACT244, CD74AC244, CD74AC244, CD74AC244, CD74ACT241, CD74ACT244:



#### **PACKAGE OPTION ADDENDUM**

4-Feb-2021

- Catalog: CD74AC240, CD74AC244, CD74ACT240, CD74ACT241, CD74ACT244
- Military: CD54AC240, CD54AC244, CD54ACT240, CD54ACT241, CD54ACT244

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

### PACKAGE MATERIALS INFORMATION

www.ti.com 18-Aug-2014

#### TAPE AND REEL INFORMATION





A0	
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC240M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74AC244M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT240M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT241M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT244M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

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\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC240M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74AC244M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74ACT240M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74ACT241M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74ACT244M96	SOIC	DW	20	2000	367.0	367.0	45.0

#### 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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